

PS9013

R08DS0136EJ0100 Rev.1.00 Mar 11, 2016

1 Mbps, OPEN COLLECTOR OUTPUT, HIGH CMR, IPM DRIVER, 5-PIN SSOP (LSO5) PHOTOCOUPLER

DESCRIPTION

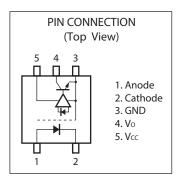
The PS9013 is an optically coupled isolator containing a GaAlAs LED on the input side and a photo diode and a signal processing circuit on the output side on one chip. The PS9013 is specified high CMR and pulse width distortion with operating temperature. It is suitable for IPM drive.

FEATURES

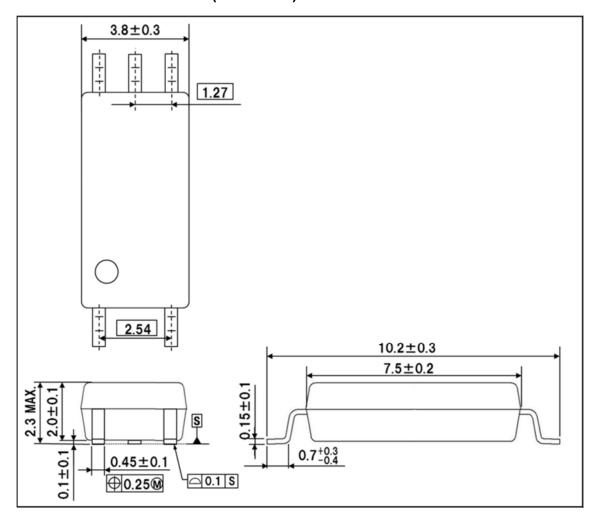
- Long creepage distance (8 mm MIN.)
- High common mode transient immunity (CM_H, CM_L = $\pm 50 \text{ kV/}\mu\text{s}$ MIN.)
- Operating Ambient Temperature (125 °C MAX.)
- High-speed response ($t_{PHL} = 500 \text{ ns MAX.}$, $t_{PLH} = 750 \text{ ns MAX.}$)
- Maximum propagation delays $(t_{PLH} t_{PHL} = 270 \text{ ns TYP.})$
- High isolation voltage (BV = 5 000 Vr.m.s.)
- Open collector output
- Embossed tape product: PS9013-F3: 3 000 pcs/reel
- Pb-Free product
- · Safety standards
 - UL approved: UL1577, Double protection
 - CSA approved: CA5A, CAN/CSA-C22.2 60065, CAN/CSA-C22.2 60950-1, Reinforced insulation)
 - VDE approval: DIN EN 60747-5-5 (Option)

APPLICATIONS

- IPM Driver
- General purpose inverter



PACKAGE DIMENSIONS (UNIT: mm)

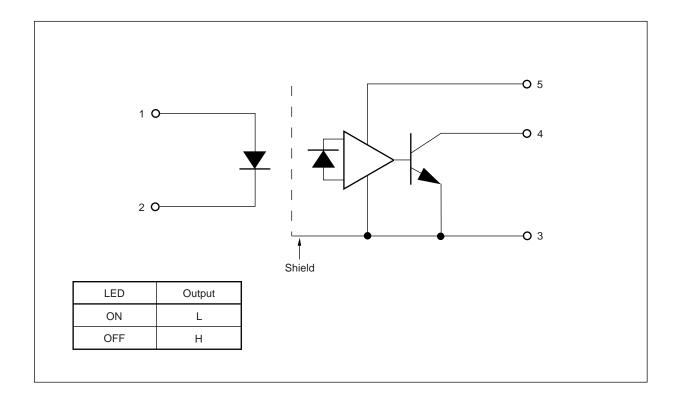


Weight: 0.119g (typ.)

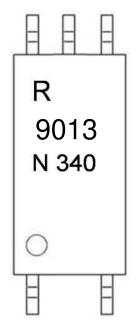
PHOTOCOUPLER CONSTRUCTION

Parameter	MIN.
Air Distance	8 mm
Outer Creepage Distance	8 mm
Isolation Distance	0.15 mm

BLOCK DIAGRAM



MARKING EXAMPLE



R		An i	An initial of "Renesas"			
9013		Proc	Product Part Number			
0		No.	No.1 pin Mark, Anode Mark			
N340	N	Ran	Rank Code			
340		Ass	embly Lot			
		3	Last one-digit of Assembly Year			
		40	Weekly Serial Code			

ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number*1
PS9013	PS9013-Y-AX	Pb-Free and	20 pcs (Tape 20 pcs cut)	Standard products	PS9013
PS9013-F3	PS9013-Y-F3-AX	Halogen Free	Embossed Tape 3 000	(UL,CSA approved)	
		(Ni/Pd/Au)	pcs/reel		
PS9013-V	PS9013-Y-V-AX		20 pcs (Tape 20 pcs cut)	UL,CSA approved	
PS9013-V-F3	PS9013-Y-V-F3-AX		Embossed Tape 3 000	DIN EN 60747-5-5	
			pcs/reel	(VDE 0884-5):	
				2011-11 approved	
				(Option)	

Note: *1. For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise specified)

	Parameter	Symbol	Ratings	Unit
Diode	Forward Current*1	lF	25	mA
	Reverse Voltage	V _R	5	V
Detector	Supply Voltage	V _{CC}	−0.5 to +30	V
	Output Voltage	Vo	−0.5 to +30	V
	Output Current	l ₀	15	mA
	Power Dissipation*2	Pc	250	mW
Isolation Vol	tage *3	BV	5 000	Vr.m.s.
Operating A	mbient Temperature	T _A	-40 to +125	°C
Storage Ten	nperature	T _{stg}	−55 to +150	°C

Notes: *1. Reduced to 0.325 mA/ $^{\circ}$ C at T_A = 85 $^{\circ}$ C or more.

Pins 1-3 shorted together, 4-6 shorted together.

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Supply Voltage	Vcc	4.5	15	25	V
Forward Current (ON)	I _{F (ON)}	8		12	mA
Forward Voltage (OFF)	V _F (OFF)	-2		0.8	V

^{*2.} Reduced to 4.15 mW/°C at $T_A = 85$ °C or more

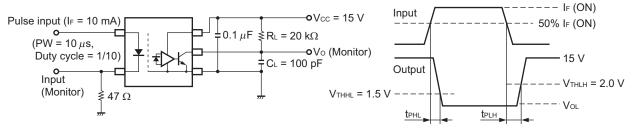
^{*3.} AC voltage for 1 minute at $T_A = 25$ °C, RH = 60% between input and output.

ELECTRICAL CHARACTERISTICS ($T_A = -40$ to +125°C, $V_{CC} = 15$ V, unless otherwise specified)

	Parameter	Symbol	Conditions	MIN.	TYP. ^{*1}	MAX.	Unit
Diode	Forward Voltage	V_{F}	I _F = 10 mA	1.35	1.56	1.75	V
	Reverse Current	I _R	V _R = 3 V			10	μA
	Terminal Capacitance	Ct	V = 0 V, f = 1 MHz, T _A = 25°C		30		pF
Detector	Low Level Output Voltage	V _{OL}	$I_F = 10 \text{ mA}, I_{OL} = 2.4 \text{ mA}$		0.13	0.6	V
	High Level Output Current	I _{OH}	$V_{CC} = V_O = 20 \text{ V}, V_F = 0.8 \text{ V}$		0.01	50	μA
	High Level Supply Current	I _{CCH}	$V_{CC} = 20 \text{ V}, V_F = 0.8 \text{ V}, V_O = \text{open}$		1.0	1.3	mA
	Low Level Supply Current	I _{CCL}	$V_{CC} = 20 \text{ V}, I_F = 10 \text{ mA}, V_O = \text{open}$		1.0	1.3	mA
Coupled	Threshold Input Current $(H \rightarrow L)$	I _{FHL}	$V_O = 0.8 \text{ V}, I_O = 0.75 \text{ mA}$		1.5	5.0	mA
	Isolation Resistance	R _{I-O}	$V_{I-O} = 1 \text{ kV}_{DC}, \text{ RH} = 40 \text{ to } 60\%,$ $T_A = 25^{\circ}\text{C}$	10 ¹¹			Ω
	Isolation Capacitance	C _{I-O}	V = 0 V, f = 1 MHz, TA = 25°C		0.7		pF
	Propagation Delay Time $(H \rightarrow L)^{*2}$	t _{PHL}	$I_F = 10 \text{ mA}, \ R_L = 20 \text{ k}\Omega, \ C_L = 100 \text{ pF},$ $V_{THHL} = 1.5 \text{ V}, \ V_{THLH} = 2.0 \text{ V}$		250	500	ns
	Propagation Delay Time $(L \rightarrow H)^{*2}$	t _{PLH}			520	750	
	Maximum Propagation Delays	t _{PLH} —t _{PHL}		-200	270	650	
	Pulse Width Distortion (PWD)*2	t _{PHL} -t _{PLH}			270	650	
	Common Mode Transient Immunity at High Level Output*3	Смн	$T_{A} = 25^{\circ}\text{C}, \ I_{F} = 0 \ \text{mA}, \ V_{O} > 3.0 \ \text{V},$ $V_{CM} = 1.5 \ \text{kV}, \ \text{RL} = 20 \ \text{k}\Omega,$ $C_{L} = 100 \ \text{pF}$	50			kV/μs
	Common Mode Transient Immunity at Low Level Output*3	C _{ML}	$\begin{split} T_{A} &= 25^{\circ}C, \ I_{F} = 10 \ mA, \ V_{O} < 1.0 \ V, \\ V_{CM} &= 1.5 \ kV, \ R_{L} = 20 \ k\Omega, \\ C_{L} &= 100 \ pF \end{split}$	50			kV/μs

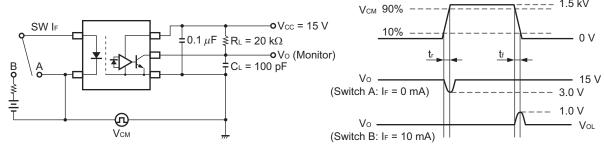
Notes*: 1. Typical values at T_A = 25°C.

2. Test circuit for propagation delay time



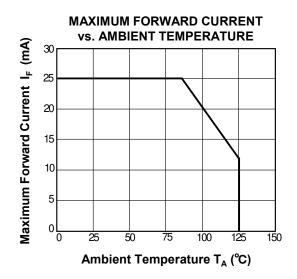
C∟ includes probe and stray wiring capacitance.

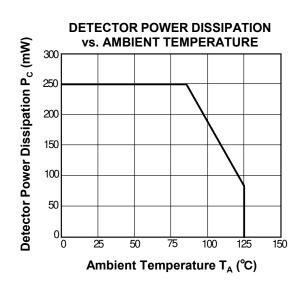
3. Test circuit for common mode transient immunity

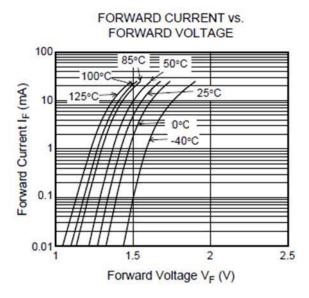


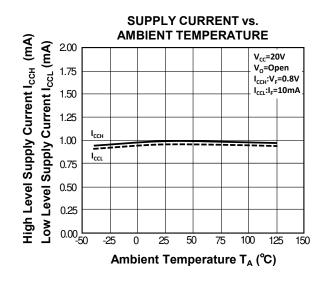
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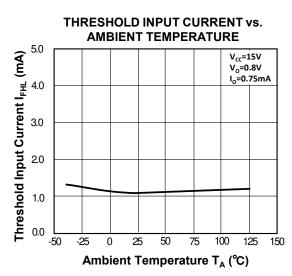
TYPICAL CHARACTERISTICS (T_A = 25°C, unless otherwise specified)

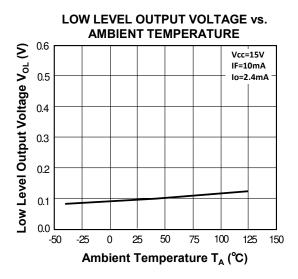






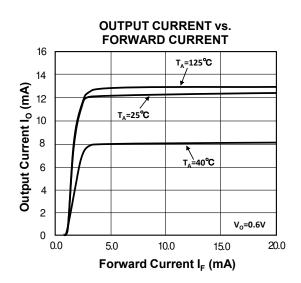


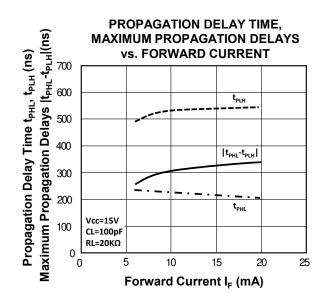


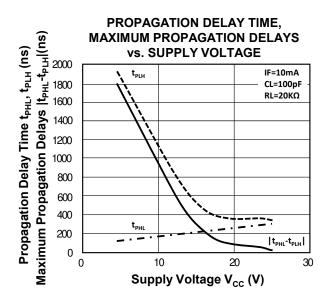


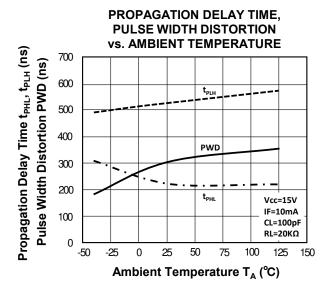
Remark The graphs indicate nominal characteristics.

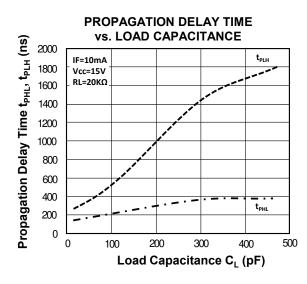
TYPICAL CHARACTERISTICS (T_A = 25°C, unless otherwise specified)

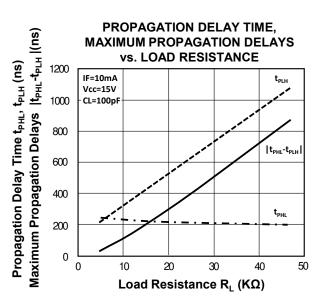






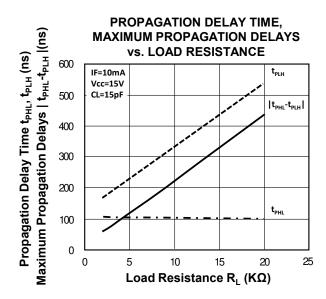






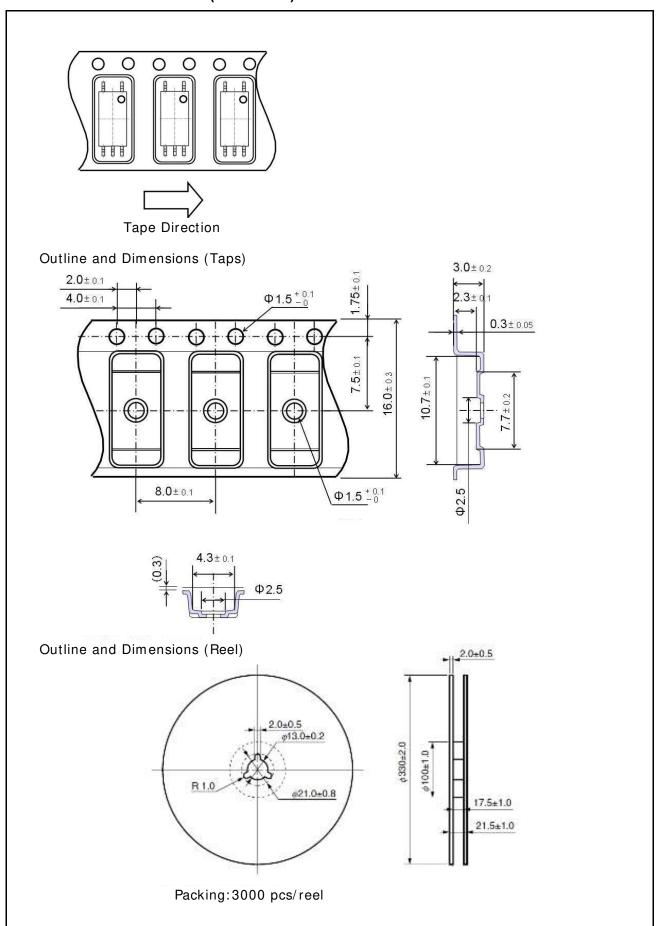
Remark The graphs indicate nominal characteristics.

TYPICAL CHARACTERISTICS (T_A = 25°C, unless otherwise specified)

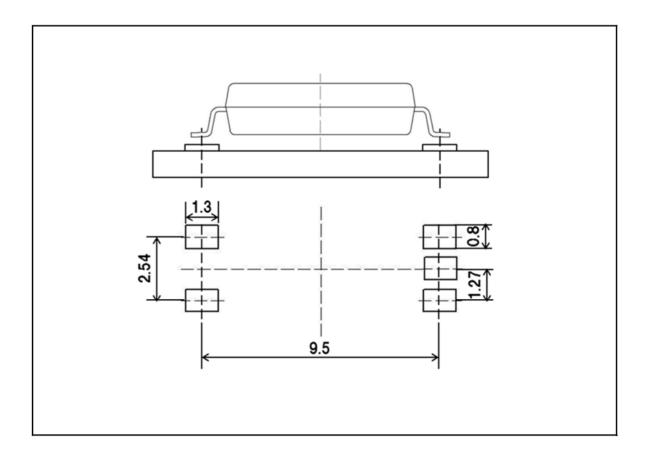


Remark The graphs indicate nominal characteristics.

TAPING SPECIFICATIONS (UNIT: mm)



RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)



Remark All dimensions in this figure must be evaluated before use.

NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

• Peak reflow temperature 260°C or below (package surface temperature)

Time of peak reflow temperature
 Time of temperature higher than 220°C
 60 seconds or less

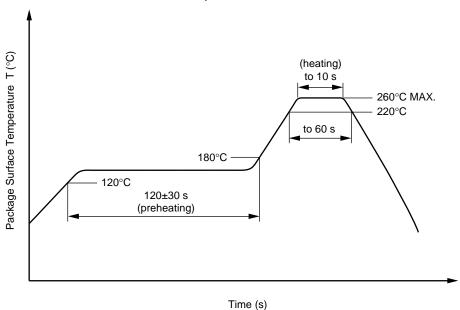
Time to preheat temperature from 120 to 180°C
 Number of reflows
 Three

• Flux Rosin flux containing small amount of chlorine (The flux

with a maximum chlorine content of 0.2 Wt% is

recommended.)

Recommended Temperature Profile of Infrared Reflow



(2) Wave soldering

• Temperature 260°C or below (molten solder temperature)

• Time 10 seconds or less

• Preheating conditions 120°C or below (package surface temperature)

• Number of times One (Allowed to be dipped in solder including plastic mold portion.)

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine

content of 0.2 Wt% is recommended.)

(3) Soldering by Soldering Iron

• Peak Temperature (lead part temperature) 350°C or below

• Time (each pins) 3 seconds or less

• Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead

(4) Cautions

• Fluxes Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

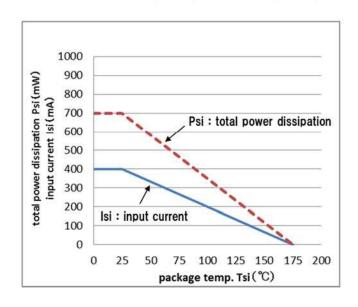
USAGE CAUTIONS

- 1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
- 2. By-pass capacitor of more than $0.1~\mu\text{F}$ is used between V_{CC} and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is no more than 10~mm.
- 3. Avoid storage at a high temperature and high humidity.

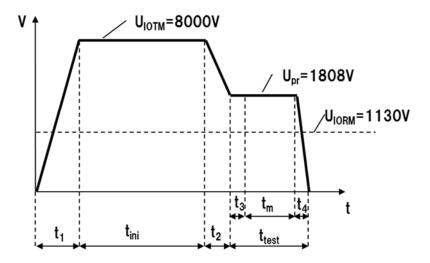
SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

Parameter	Symbol	Spec.	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		40/125/21	
Dielectric strength			
maximum operating isolation voltage	U_{IORM}	1 130	V_{peak}
Test voltage (partial discharge test, procedure a for type test and random test)	U_pr	1 808	V_{peak}
$U_{pr} = 1.6 \times U_{IORM.}, P_d < 5 pC$			
Test voltage (partial discharge test, procedure b for all devices)	U_pr	2 119	V_{peak}
$U_{pr} = 1.875 \times U_{IORM.}, P_d < 5 pC$			
Highest permissible overvoltage	U_{IOTM}	8 000	V_{peak}
Degree of pollution (DIN EN 60664-1 VDE0110 Part 1)		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303 Part 11))	CTI	400	
Material group (DIN EN 60664-1 VDE0110 Part 1)		II	
Storage temperature range	T_{stg}	-55 to +150	°C
Operating temperature range	T _A	-40 to +125	°C
Isolation resistance, minimum value			
$V_{IO} = 500 \text{ V dc at T}_A = 25^{\circ}\text{C}$	Ris MIN.	10 ¹²	Ω
V _{IO} = 500 V dc at T _A MAX. at least 100°C	Ris MIN.	10 ¹¹	Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal			
derating curve)			
Package temperature	Tsi	175	°C
Current (input current I _F , Psi = 0)	Isi	400	mA
Power (output or total power dissipation)	Psi	700	mW
Isolation resistance			
$V_{IO} = 500 \text{ V dc at } T_A = Tsi$	Ris MIN.	10 ⁹	Ω

Dependence of maximum safety ratings with package temperature

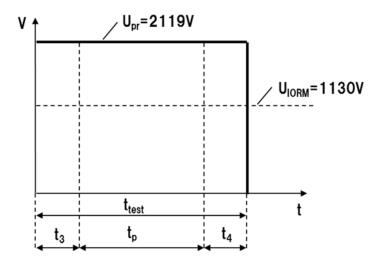


Method A Destructive Test, Type and Sample test



 t_1 , t_2 = 1 to 10 sec t_3 , t_4 = 1 sec t_m (PARTIAL DISCHARGE) = 10 sec t_{test} = 12 sec t_{ini} = 60 sec

Method b Non-destructive Test, 100% Production Test



 t_3 , t_4 =0.1 sec t_p (PARTIAL DISCHARGE) = 1.0 sec t_{test} =1.2 sec

Caution GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
 - Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.

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